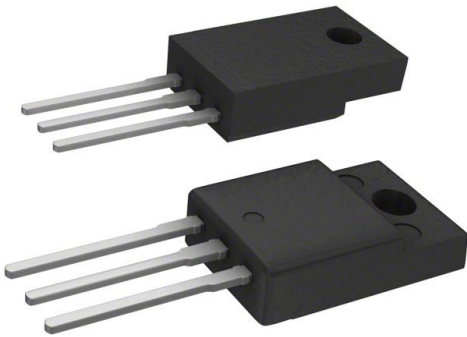


VFT10200C-E3/4W Datasheet

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DiGi Electronics Part Number	VFT10200C-E3/4W-DG
Manufacturer	Vishay General Semiconductor - Diodes Division
Manufacturer Product Number	VFT10200C-E3/4W
Description	DIODE ARR SCHOT 200V 5A ITO220AB
Detailed Description	Diode Array 1 Pair Common Cathode 200 V 5A Through Hole TO-220-3 Full Pack, Isolated Tab

This model VFT10200C-E3/4W is available at DiGi Electronics.

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Manufacturer Product Number:

VFT10200C-E3/4W

Series:

TMBS®

Diode Configuration:

1 Pair Common Cathode

Voltage - DC Reverse (Vr) (Max):

200 V

Voltage - Forward (Vf) (Max) @ If:

1.6 V @ 5 A

Current - Reverse Leakage @ Vr:

150 µA @ 200 V

Mounting Type:

Through Hole

Supplier Device Package:

ITO-220AB

Manufacturer:

Vishay General Semiconductor - Diodes Division

Product Status:

Active

Technology:

Schottky

Current - Average Rectified (Io) (per Diode):

5A

Speed:

Fast Recovery =< 500ns, > 200mA (Io)

Operating Temperature - Junction:

-40°C ~ 150°C

Package / Case:

TO-220-3 Full Pack, Isolated Tab

Base Product Number:

VFT10200

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.10.0080

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

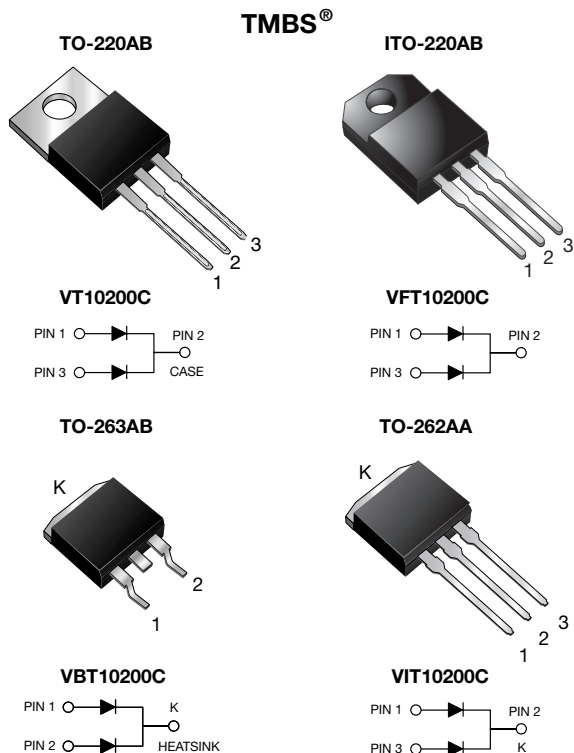


VT10200C, VFT10200C, VBT10200C, VIT10200C

Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.58\text{ V}$ at $I_F = 2.5\text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA
Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 5.0 A
V_{RRM}	200 V
I_{FSM}	80 A
V_F at $I_F = 5.0\text{ A}$	0.65 V
T_J max.	150 °C

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VT10200C	VFT10200C	VBT10200C	VIT10200C	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	200				V	
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device				10.0	A
		per diode				5.0	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	80				A	
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$, $L = 60\text{ mH}$ per diode	E_{AS}	30				mJ	
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$, 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode	I_{RRM}	0.5				A	
Voltage rate of change (rated V_R)	dV/dt	10 000				V/ μs	
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1\text{ min}$	V_{AC}	1500				V	
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150				°C	

VT10200C, VFT10200C, VBT10200C, VIT10200C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V _{BR}	200 (minimum)	-	V
Instantaneous forward voltage per diode	I _F = 2.5 A	T _A = 25 °C	V _F ⁽¹⁾	0.81	-	V
	I _F = 5.0 A			1.10	1.60	
	I _F = 2.5 A	T _A = 125 °C		0.58	-	
	I _F = 5.0 A			0.65	0.73	
Reverse current per diode	V _R = 180 V	T _A = 25 °C	I _R ⁽²⁾	1.7	-	μA
		T _A = 125 °C		1.8	-	mA
	V _R = 200 V	T _A = 25 °C		-	150	μA
		T _A = 125 °C		2.5	10	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VT10200C	VFT10200C	VBT10200C	VIT10200C	UNIT	
Typical thermal resistance	per diode	R _{θJC}	3.5	7.0	3.5	3.5	°C/W
	per device		2.5	5.5	2.5	2.5	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	VT10200C-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VFT10200C-E3/4W	1.72	4W	50/tube	Tube
TO-263AB	VBT10200C-E3/4W	1.37	4W	50/tube	Tube
TO-263AB	VBT10200C-E3/8W	1.37	8W	800/reel	Tape and reel
TO-262AA	VIT10200C-E3/4W	1.44	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

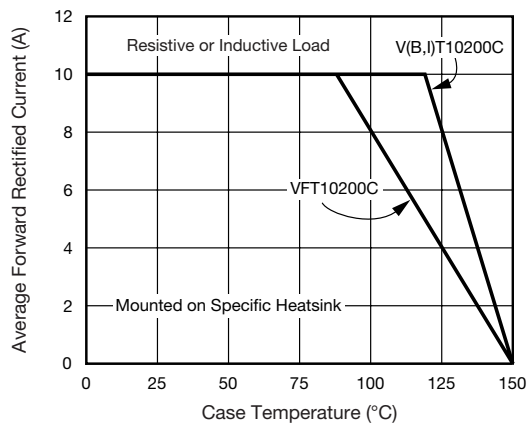


Fig. 1 - Maximum Forward Current Derating Curve

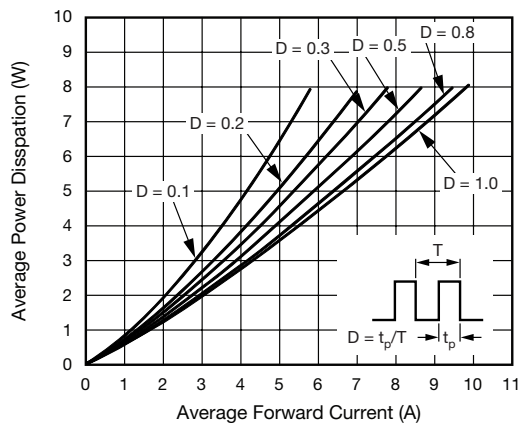


Fig. 2 - Forward Power Loss Characteristics Per Device



VT10200C, VFT10200C, VBT10200C, VIT10200C

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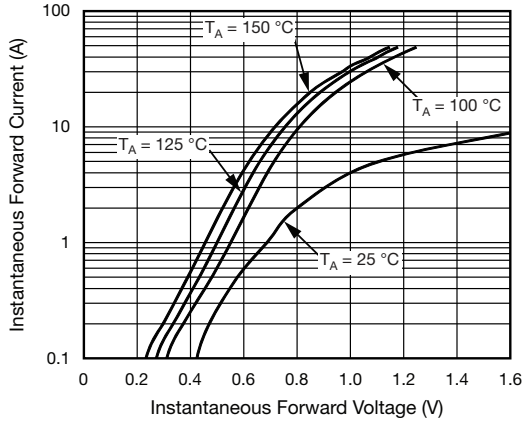


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

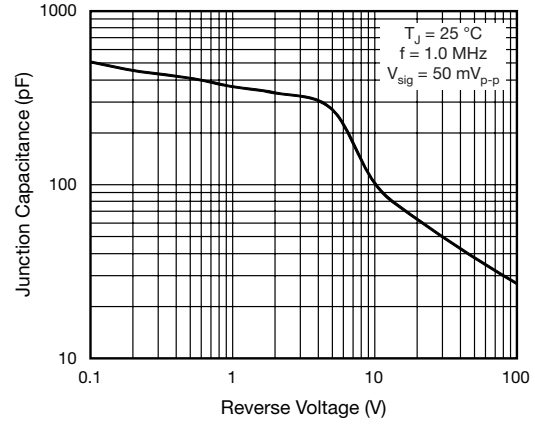


Fig. 5 - Typical Junction Capacitance Per Diode

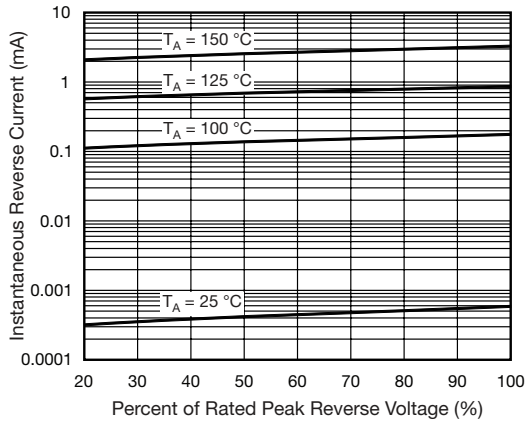


Fig. 4 - Typical Reverse Characteristics Per Diode

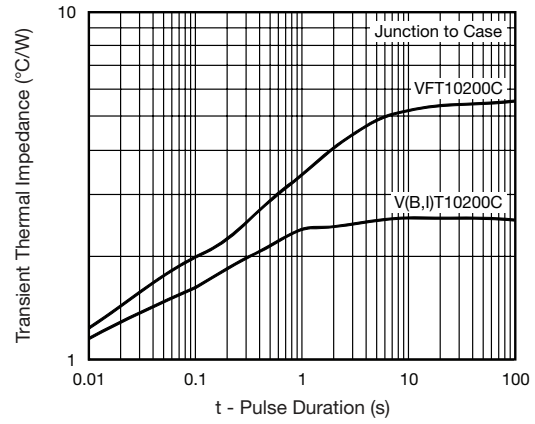


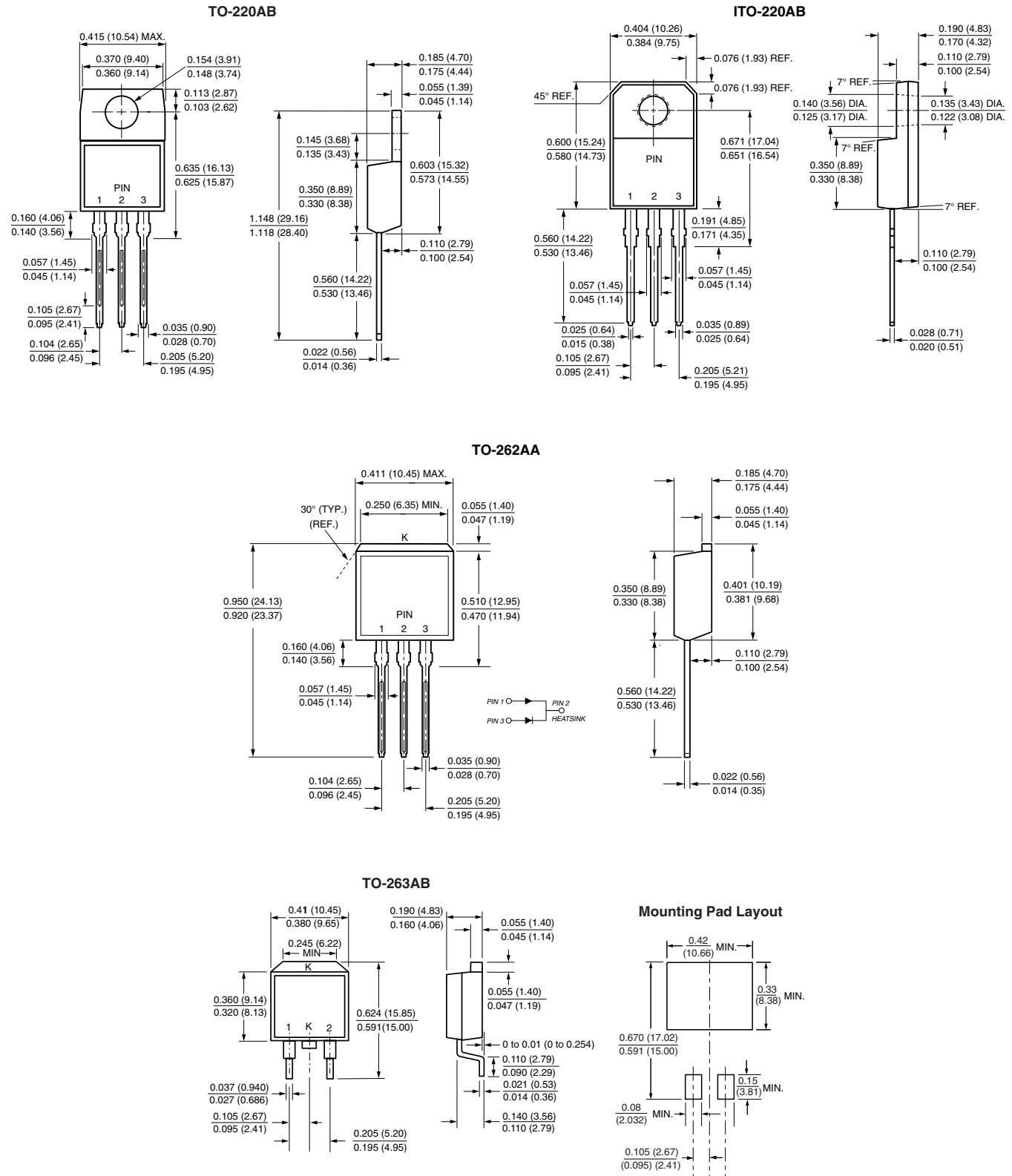
Fig. 6 - Typical Transient Thermal Impedance Per Device

VT10200C, VFT10200C, VBT10200C, VIT10200C

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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